



A Product Line of **Diodes Incorporated** 



### Features

- BV<sub>CEO</sub> > 75V
- I<sub>c</sub> = 3A high Continuous Current
- I<sub>CM</sub> = 10A Peak Pulse Current
- High Gain Holds up h<sub>FE</sub> > 300 @ I<sub>C</sub>=1A
- Low Equivalent On-Resistance; R<sub>CE(sat)</sub> = 78mΩ at 4.5A
- Excellent hFE characteristics up to 10A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

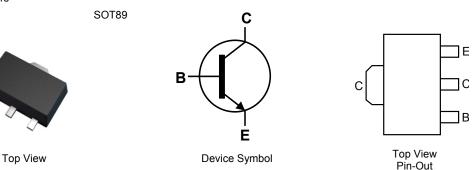
# Applications

- **Emergency Lighting Circuits**
- Motor Driving (including DC fans)
- Solenoid, Relay and Actuator Drivers
- DC DC Modules
- Backlight Inverters
- **Power Switches**
- **MOSFET Gate Drivers**



### Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)



### Ordering Information (Note 4)

| Part Number  | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|--------------|---------|--------------------|-----------------|-------------------|
| FCX1053ATA   | 053     | 7                  | 12              | 1,000             |
| FCX1053A-13R | 053     | 13                 | 12              | 4,000             |

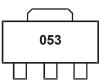
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

Notes:

and Lead-free 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



053 = Product Type Marking Code





#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | 150   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | 75    | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | 7     | V    |
| Continuous Collector Current | Ic               | 3     | А    |
| Base Current                 | IB               | 500   | mA   |
| Peak Pulse Current           | I <sub>CM</sub>  | 10    | А    |

#### **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                              | Symbol                           | Value            | Unit |      |  |
|---|----------------------------------|------------------|------|------|--|
|   | (Note 5)                         |                  | 1    |      |  |
| Power Dissipation                           | (Note 6)                         | PD               | 1.6  | W    |  |
|   | (Note 7)                         |                  | 2.0  |      |  |
|   | (Note 5)                         |                  | 125  |      |  |
| Thermal Resistance, Junction to Ambient Air | (Note 6)                         | R <sub>0JA</sub> | 78   | °C/W |  |
|   | (Note 7)                         |                  | 62.5 |      |  |
| Thermal Resistance, Junction to Lead        | (Note 8)                         | $R_{\theta JL}$  | 3.6  | °C/W |  |
| Operating and Storage Temperature Range     | T <sub>J,</sub> T <sub>STG</sub> | -55 to +150      | °C   |      |  |

#### ESD Ratings (Note 9)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | С           |

Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

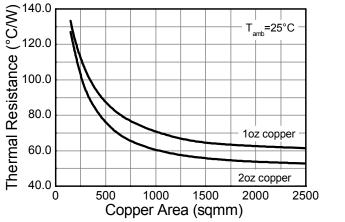
6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

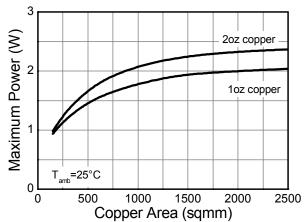
7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.

8. Thermal resistance from junction to solder-point (on the exposed collector pad).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

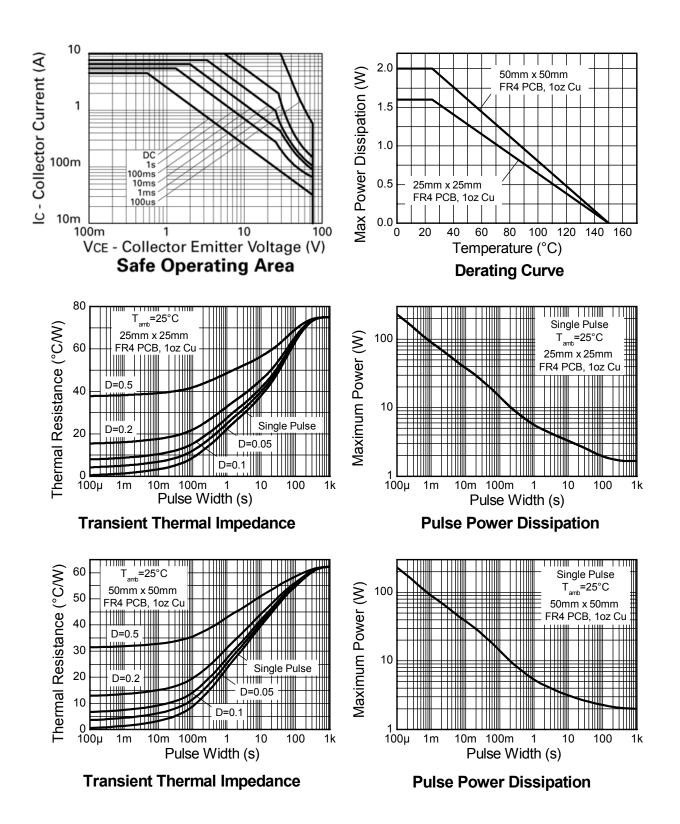
## Thermal Characteristics and Derating Information













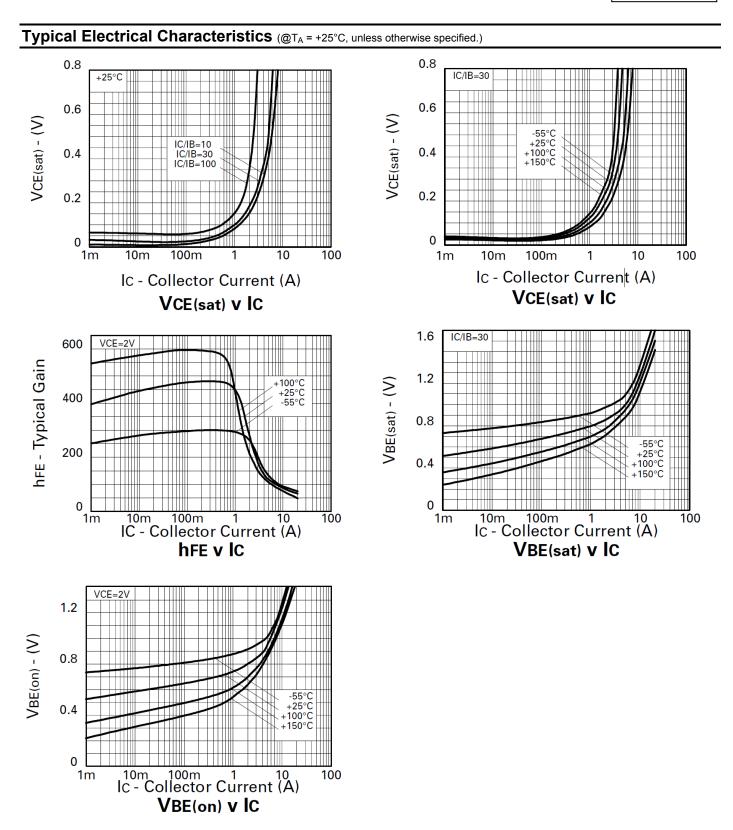


| Electrical Characteristics (@T <sub>A</sub> = +25°C, unless otherwise specified.) |                      |                         |                               |                               |      |   |
|---|----------------------|-------------------------|-------------------------------|-------------------------------|------|---|
| Characteristic  | Symbol               | Min                     | Тур                           | Max                           | Unit | Test Condition  |
| Collector-Base Breakdown Voltage  | BV <sub>CBO</sub>    | 150                     | 250                           | —                             | V    | I <sub>C</sub> = 100μA  |
| Collector-Emitter Breakdown Voltage   | BV <sub>CES</sub>    | 150                     | 250                           | —                             | V    | I <sub>C</sub> = 100μA  |
| Collector-Emitter Breakdown Voltage (Notes 10)                                    | BV <sub>CEO</sub>    | 75                      | 100                           | —                             | V    | I <sub>C</sub> = 10mA   |
| Collector-Emitter Breakdown Voltage   | BVCEV                | 150                     | 250                           | —                             | V    | I <sub>C</sub> = 100μA, V <sub>EB</sub> = 1V  |
| Emitter-Base Breakdown Voltage  | BVEBO                | 7                       | 8.8                           | _                             | V    | I <sub>E</sub> = 100μA  |
| Collector Cutoff Current  | Ісво                 | _                       | 0.9                           | 50                            | nA   | V <sub>CB</sub> = 120V  |
| Collector Cutoff Current  | I <sub>CES</sub>     | _                       | 1.5                           | 50                            | nA   | V <sub>CES</sub> = 120V   |
| Emitter Cutoff Current  | I <sub>EBO</sub>     | —                       | 0.3                           | 20                            | nA   | V <sub>EB</sub> = 5.6V  |
| DC current transfer Static ratio (Notes 10)                                       | h <sub>FE</sub>      | 270<br>300<br>300<br>40 | 440<br>450<br>450<br>60<br>20 | 1200                          |      | $\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 0.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 1 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 4.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 10 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$ |
| Collector-Emitter Saturation Voltage (Notes 10)                                   | V <sub>CE(sat)</sub> | _                       | 21<br>55<br>150<br>160<br>350 | 30<br>75<br>200<br>210<br>440 | mV   | $\begin{split} I_{C} &= 0.2A, \ I_{B} = 20mA \\ I_{C} &= 0.5A, \ I_{B} = 20mA \\ I_{C} &= 1A, \ I_{B} = 10mA \\ I_{C} &= 2A, \ I_{B} = 100mA \\ I_{C} &= 4.5A, \ I_{B} = 200mA \end{split}$   |
| Base-Emitter Saturation Voltage (Notes 10)  | V <sub>BE(sat)</sub> | —                       | 900                           | 1000                          | mV   | I <sub>C</sub> = 3A, I <sub>B</sub> = 100mA   |
| Base-Emitter Turn-on Voltage (Notes 10)   | V <sub>BE(on)</sub>  | —                       | 825                           | 950                           | mV   | $I_{C}$ = 3A, $V_{CE}$ = 2V   |
| Transitional Frequency  | f⊤                   | _                       | 140                           | _                             | MHz  | I <sub>C</sub> = 50mA, V <sub>CE</sub> = 10V,<br>f = 100MHz   |
| Output capacitance  | C <sub>obo</sub>     | _                       | 21                            | 30                            | pF   | V <sub>CB</sub> = 10V, f = 1MHz,  |
| Switching Time  | t <sub>on</sub>      |                         | 162                           |                               | ns   | V <sub>CC</sub> = 50V, I <sub>C</sub> = 2A,   |
| Switching Time  | t <sub>off</sub>     | ] —                     | 900                           |                               | ns   | $I_{B1} = I_{B2} = \pm 20 \text{mA}$  |

Note: 10. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .





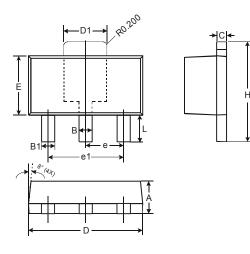






### **Package Outline Dimensions**

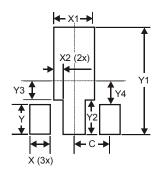
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT89                |            |      |  |  |
|----------------------|------------|------|--|--|
| Dim                  | Min Max    |      |  |  |
| Α                    | 1.40 1.60  |      |  |  |
| В                    | 0.44       | 0.62 |  |  |
| B1                   | 0.35       | 0.54 |  |  |
| С                    | 0.35       | 0.43 |  |  |
| D                    | 4.40 4.60  |      |  |  |
| D1                   | 1.52       | 1.83 |  |  |
| ш                    | 2.29 2.60  |      |  |  |
| е                    | e 1.50 Typ |      |  |  |
| e1                   | 3.00 Typ   |      |  |  |
| Н                    | 3.94 4.25  |      |  |  |
| L                    | 0.89 1.20  |      |  |  |
| All Dimensions in mm |            |      |  |  |

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Х          | 0.900         |
| X1         | 1.733         |
| X2         | 0.416         |
| Y          | 1.300         |
| Y1         | 4.600         |
| Y2         | 1.475         |
| Y3         | 0.950         |
| Y4         | 1.125         |
| С          | 1.500         |





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